NSN 5962-01-353-8042

Memory Microcircuit - Page 1 of 2



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Port to contract the second se
Body Length:
1.260 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and monolithic and static operation
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
19 input
Current Rating Per Characteristic:
90.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
8.00 input picofarads and 10.00 output picofarads
Time Rating Per Chacteristic:
35.00 nanoseconds access
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a
Unit Of Measure:

NSN 5962-01-353-8042

Memory Microcircuit - Page 2 of 2



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No

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